

ROHS COMPLIANT

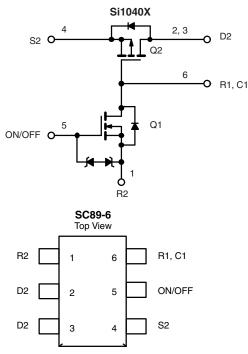
HALOGEN

FREE

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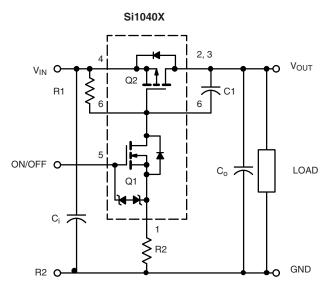
Load Switch with Level-Shift

PRODUCT	SUMMARY	
V _{DS2} (V)	R_{DS(on)} (Ω)	I _D (A)
	0.625 at V _{IN} = 4.5 V	± 0.43
1.8 to 8	0.890 at V _{IN} = 2.5 V	± 0.36
	1.25 at V _{IN} = 1.8 V	± 0.3



Ordering Information: Si1040X-T1-GE3 (Lead (Pb)-free and Halogen-free)

TYPICAL APPLICATION CIRCUIT

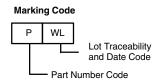


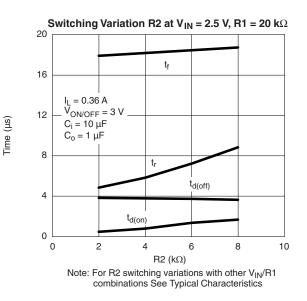
FEATURES

- Halogen-free According to IEC 61249-2-21
 Definition
- TrenchFET[®] Power MOSFET
- 1.8 V to 8 V Input
- 1.5 V to 8 V Logic Level Control
- Smallest LITTLE FOOT[®] Package: 1.6 mm x 1.6 mm
- 2000 V ESD Protection On Input Switch, V_{ON/OFF}
- Adjustable Slew-Rate
- Compliant to RoHS Directive 2002/95/EC

DESCRIPTION

The Si1040X includes a p- and n-Channel MOSFET in a single SC89-6 package. The low on-resistance p-channel TrenchFET is tailored for use as a load switch. The n-channel, with an external resistor, can be used as a level-shift to drive the p-channel load-switch. The n-channel MOSFET has internal ESD protection and can be driven by logic signals as low as 1.5 V. The Si1040X operates on supply lines from 1.8 V to 8 V, and can drive loads up to 0.43 A.





Document Number: 71809 S10-2544-Rev. D, 08-Nov-10

Si1040X

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CO	PONENTS	
R1	Pull-Up Resistor	Typical 10 k Ω to 1 m Ω^a
R2	Optional Slew-Rate Control	Typical 0 to 100 $k\Omega^a$
C1	Optional Slew-Rate Control	Typical 1000 pF

The Si1040X is ideally suited for high-side load switching in portable applications. The integrated N-Channel level-shift device saves space by reducing external components. The slew rate is set externally so that rise-times can be tailored to different load types.

Notes:

a. Minimum R1 value should be at least 10 x R2 to ensure Q1 turnon.

ABSOLUTE MAXIMUM RATINGS (T _A = 25	°C, unless otherw	vise noted)			
Parameter		Symbol	Limit	Unit	
Input Voltage		V _{IN}	8	V	
ON/OFF Voltage		V _{ON/OFF}	8	v	
Load Current	Continuous ^{a, b}	I.	± 0.43		
Load Guilent	Pulsed ^{b, c}	۱L	± 1.0	А	
Continuous Intrinsic Diode Conduction ^a		۱ _S	- 0.15		
Maximum Power Dissipation ^a		PD	0.174	W	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150	°C	
ESD Rating, MIL-STD-883D Human Body Model (100 pF, 1500 Ω)		ESD	2	kV	

THERMAL RESISTANCE RATINGS				
Parameter	Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient (Continuous Current) ^a	R _{thJA}	600	720	°C/W
Maximum Junction-to-Foot (Q2)	R _{thJC}	450	540	0/11

Notes:

a. Surface mounted on 1" x 1" FR4 board.

SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)						
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
OFF Characteristics						
Reverse Leakage Current	I _{FL}	$V_{IN} = 8 V, V_{ON/OFF} = 0 V$			1	μA
Diode Forward Voltage	V _{SD}	I _S = - 0.15 A		0.85	1.2	V
ON Characteristics				•	•	
Input Voltage Range	V _{IN}		1.8		8	V
		$V_{ON/OFF}$ = 1.5 V, V_{IN} = 4.5 V, I_D = 0.43 A		0.500	0.625	
On-Resistance (P-Channel) at 1 A	R _{DS(on)}	$V_{ON/OFF}$ = 1.5 V, V_{IN} = 2.5 V, I_D = 0.36 A		0.710	0.890	Ω
		$V_{ON/OFF}$ = 1.5 V, V_{IN} = 1.8 V, I_D = 0.3 A		1.0	1.25	1
	1	$V_{\text{IN-OUT}} \leq 0.2$ V, V_{IN} = 5 V, $V_{\text{ON/OFF}}$ = 1.5 V	1			А
On-State (P-Channel) Drain Current	I _{D(on)}	$V_{IN\text{-}OUT}{\leq}0.3$ V, V_{IN} = 3 V, $V_{ON/OFF}$ = 1.5 V	0.8			

Notes:

a. Surface mounted on FR4 board.

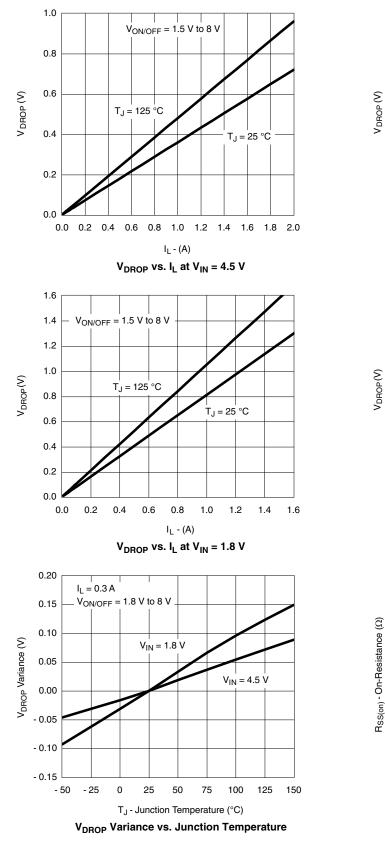
b. $V_{IN} = 8 V$, $V_{ON/OFF} = 8 V$, $T_A = 25 \ ^{\circ}C$.

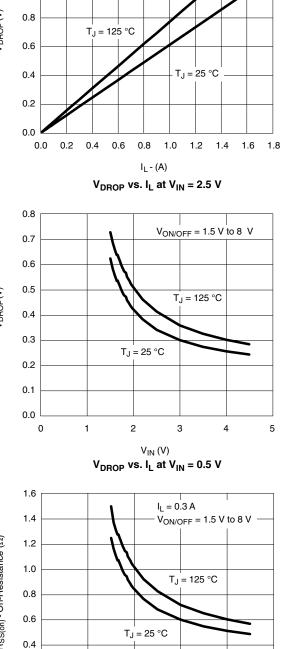
c. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)





2

V_{IN} (V)

On-Resistance vs. Input Voltage

3

1.4

1.2

1.0

0.2

0.0

0

1

 $V_{ON/OFF} = 1.5 V \text{ to } 8$

5

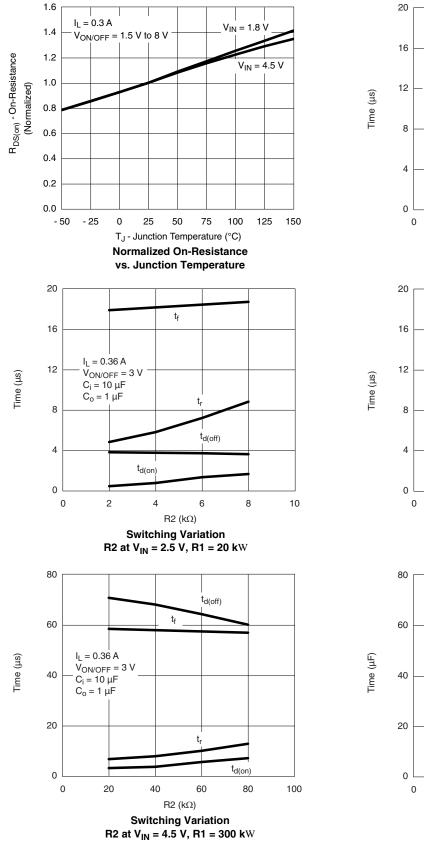
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Si1040X

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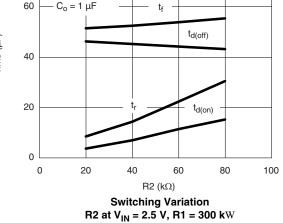


TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



 $I_{L} = 0.36 \text{ A}$ $\overline{V}_{ON/OFF} = 3 V$ $C_{i} = 10 \, \mu F$ $C_o = 1 \ \mu F$ t_{d(off)} tr t_{d(on)} 2 6 8 10 4 R2 (kΩ) **Switching Variation** R2 at $V_{IN} = 4.5$ V, R1 = 20 kW tf $I_{L} = 0.36'A$ V_{ON/OFF} = 3 V $C_i = 10 \ \mu F$ $C_0 = 1 \mu F$ t_{d(off)} t_{d(on)} 4 10 2 6 8 R2 (kΩ) **Switching Variation** R2 at V $_{\text{IN}}$ = 1.8 V, R1 = 20 kW $I_1 = 0.36 A$ V_{ON/OFF} = 3 V $C_i = 10 \ \mu F$ $C_0 = 1 \mu F$ t_f

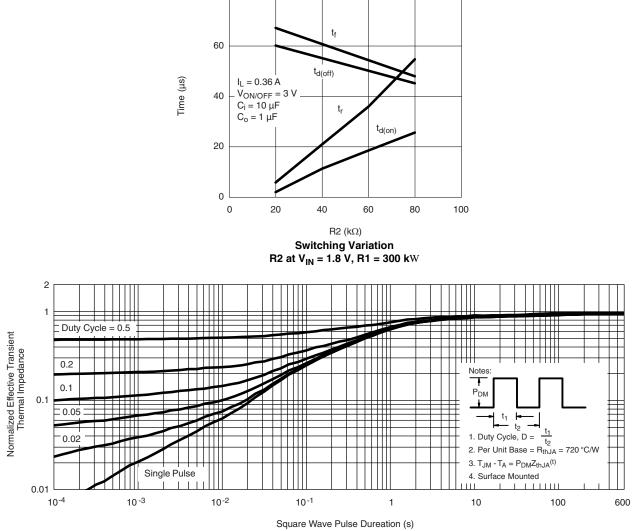
tf





TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

80



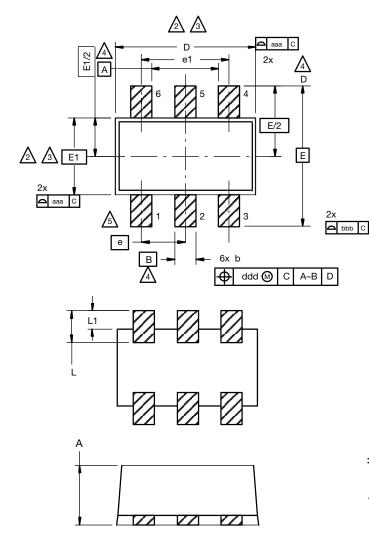
Normalized Thermal Transient Impedance, Junction-to-Ambient

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71809.



Vishay Siliconix

SC-89 6-Leads (SOT-563F)



Notes

- 1. Dimensions in millimeters.
- Dimension D does not include mold flash, protrusions or gate burrs. Mold flush, protrusions or gate burrs shall not exceed 0.15 mm per dimension E1 does not include interlead flash or protrusion, interlead flash or protrusion shall not exceed 0.15 mm per side.
- Dimensions D and E1 are determined at the outmost extremes of the plastic body exclusive of mold flash, the bar burrs, gate burrs and interlead flash, but including any mismatch between the top and the bottom of the plastic body.

A Datums A, B and D to be determined 0.10 mm from the lead tip.

 \triangle Terminal numbers are shown for reference only.

These dimensions apply to the flat section of the lead between 0.08 mm and 0.15 mm from the lead tip.









DIM.	MILLIMETERS				
	MIN.	NOM.	MAX.		
А	0.56	0.58	0.60		
A1	0	0.02	0.10		
b	0.15	0.22	0.30		
С	0.10	0.14	0.18		
D	1.50	1.60	1.70		
E	1.50	1.60	1.70		
E1	1.15	1.20	1.25		
е	0.45	0.50	0.55		
e1	0.95	1.00	1.05		
L	0.25	0.35	0.50		
L1	0.10	0.20	0.30		
C14-0439-Rev DWG: 5880	v. C, 11-Aug-14				

Revision: 11-Aug-14

1 For technical questions, contact: <u>analogswitchtechsupport@vishay.com</u> Document Number: 71612

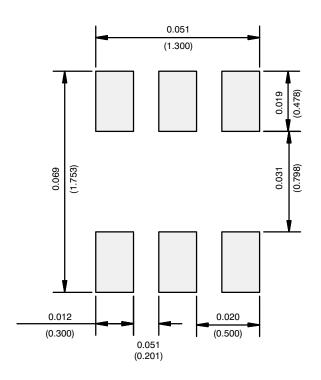
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Application Note 826

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RECOMMENDED MINIMUM PADS FOR SC-89: 6-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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